







## Mechanosynthesis of new lead-free perovskites as potential absorbers for photovoltaics.

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## Introducion

In a remarkably short period of time, metal-halide perovskites have gone from relative obscurity to an intensely studied class of materials. The efficiencies of solar cells constructed from lead-halide perovskites have risen from 3,8% in a dye-sensitized solar cell configuration to NREL certified 21,2% in planar heterojunction cells [1]. Despite its good opto-electrical properties, MAPbl<sub>3</sub> possesses two main drawbacks that hampers further commercialization: (a) moisture sensitivity and (b) high toxicity due to lead content. Therefore finding good perovskite absorbers composed of non-toxic metals is one of main topics in perovskite chemistry.

One of the most promising candidates for Pb<sup>2+</sup> replacement is Bi<sup>3+</sup> because it is **environment friendly** and both ions got isoelectronic structure. There are known several materials among perovskite family containing bismuth ions eg.: Cs<sub>2</sub>AgBiCl<sub>6</sub> [2] (double perovskite) or MA<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub> [3] (so called "0D" perovskite). Most of those materials got relatively high bangap ~2 eV, so their applications are limited to tandem solar cells.

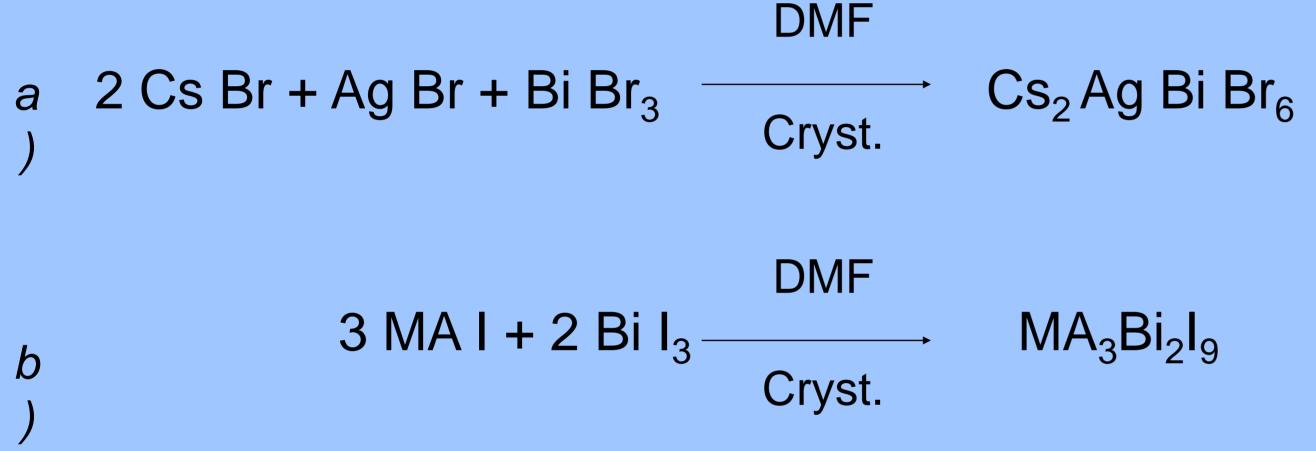


Fig. 1. Literature synthesis of bismuth(III) perovskites a) Cs<sub>2</sub>AgBiX<sub>6</sub>, b) MA<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub>

### **Bandgap and t-factor tuning** by ion mixing

- MA Pb  $I_{3-a}X_a$  (X = Cl, Br)
  - MA<sub>1-a</sub>FA<sub>a</sub>PbI<sub>3</sub>
  - MAPb<sub>1-a</sub>Cd<sub>a</sub>I<sub>3</sub>
    - Tuning of halide

#### **Lead substitution**

- $\bullet$  A<sub>2</sub>PbM(II)I<sub>6</sub>
- Cs<sub>2</sub>Ag(I)Bi(III)Br<sub>6</sub>
- <u>A</u><sub>2</sub>M(I) M(III)X<sub>6</sub>

#### **Higher stability**

- MA substitution with inorganic ions (eg. Cs+)
  - Layered perovskites
  - Perovskite encapsulation

perovskite properties

#### "0D" materials

- A<sub>a</sub>M<sub>b</sub>I<sub>c</sub> (M=Pb, Sn, Bi,...)
  - <u>A<sub>3</sub>Bi<sub>2</sub>I<sub>9</sub></u>
  - Other

Fig. 2. General strategies of tuning the perovskite structure.

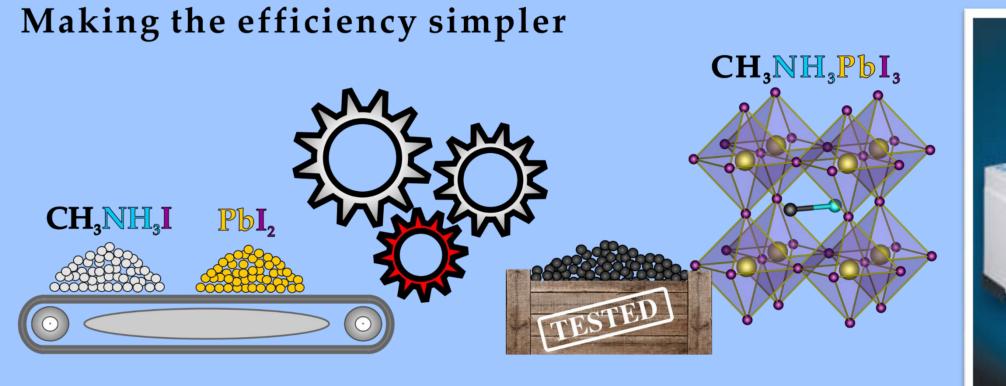




Fig. 3. Idea of applying solvent free synthesis of perovskite by high-energy ball milling mechanochemistry [4]

# Experimental

Goal of work: Design and preparation of bismuth perovskite, with bandgap shifted from ~2,0 eV (red colour) to ~1,5 eV (black colour), by mechanochemistry.

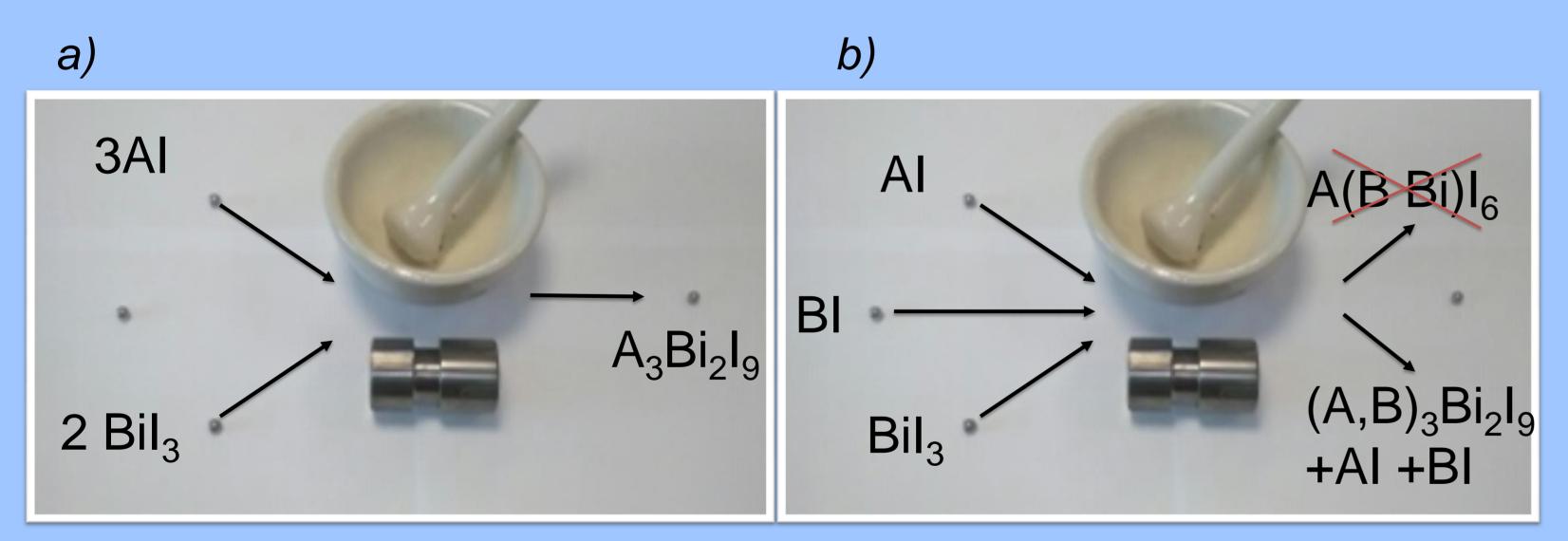
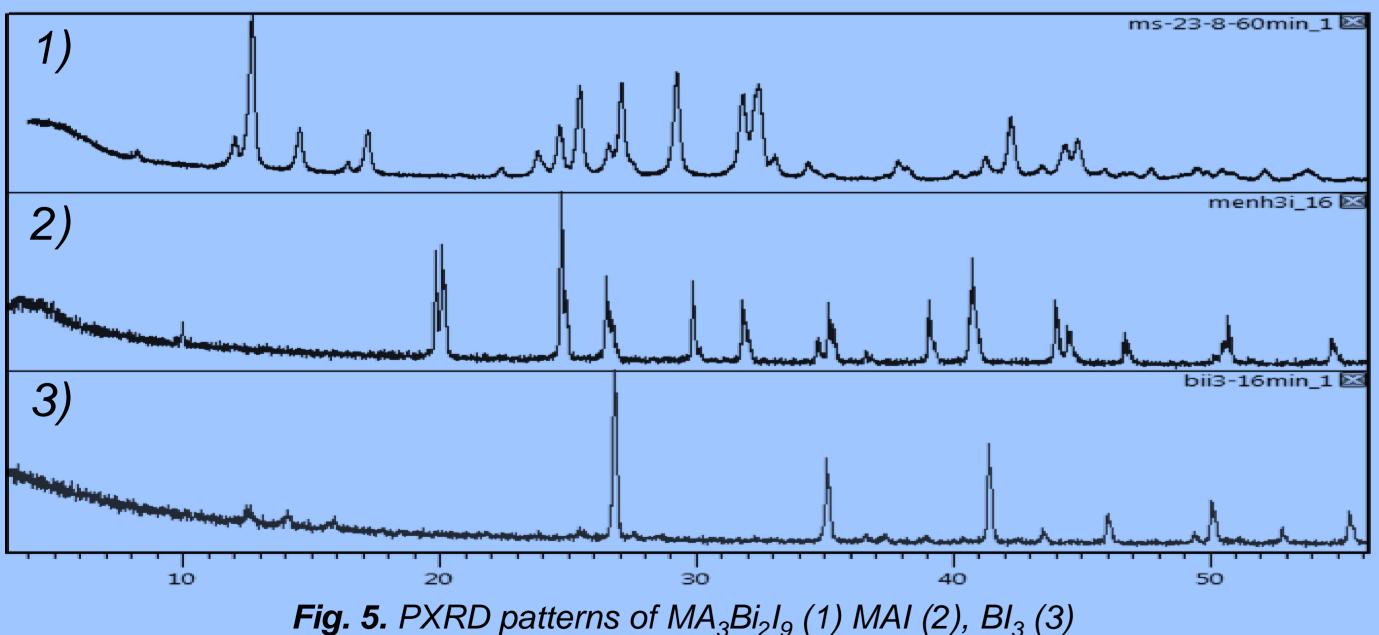


Fig. 4. Synthetical procedure of perovskite synthesis (A –big ion eg. Cs+, amines+, B – small ion eg. Li+) a) "0D perovskite", b) fail synthesis of double perovskite.



### Literature

- 1. M. Grätzel et. al., Energy Environ. Sci., 2016, Advance Article,
- 2. Hemall I Karunadasa et al. J. Am. Chem. Soc., 2016, 138 (7), pp 2138–2141
- 3. S. Kaskel et al. Chem. Commun., 2016,52, 3058-3060
- 4. D. Prochowicz, (...), M. Grätzel and J. Lewiński et. al., J. Mater. Chem. A, 2015,3, 20772-20777

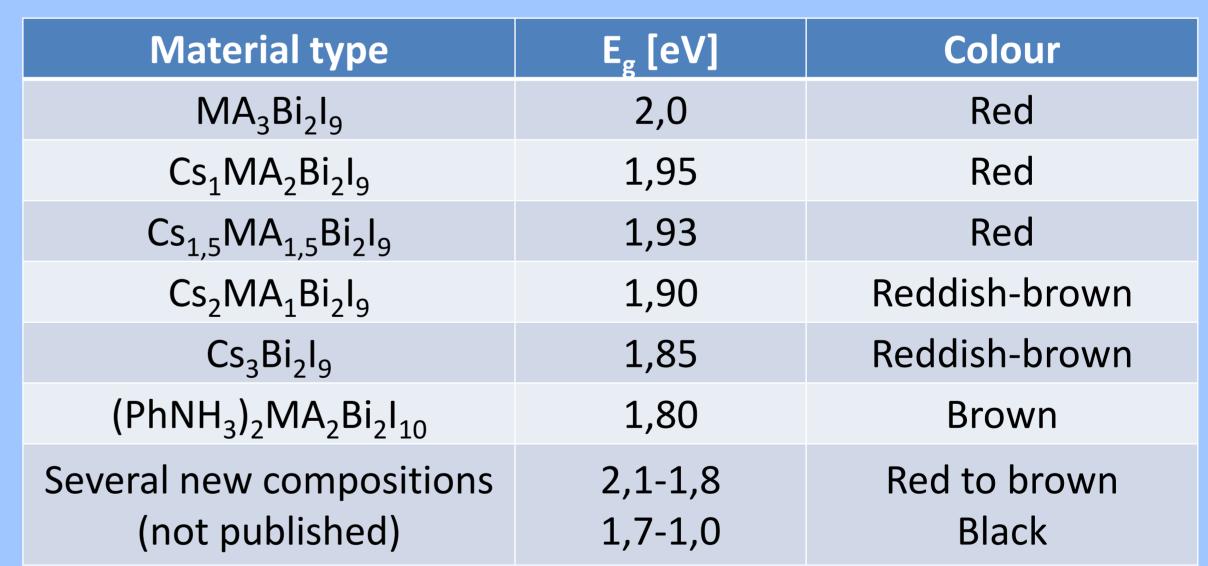




Fig. 6. Bandgap and image of selected products determined by Reflectance UVspectroskopy

### Conclusions

All materials were synthesized and charakterized by PXRD and UV spectroscopy. Some of them can be used for sollar cell preparation: (a) heterojunction architechture, (b) tandem architecture. Mechanochemistry can be applied to obtain several "0D perovskite" bismuth iodates with various compositions, but cannot be used for double perovskite synthesis.

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